

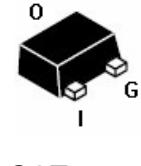
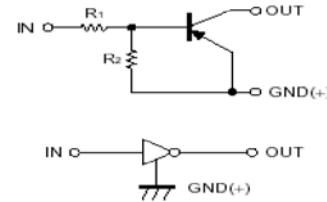
Digital Transistor

DTA(R₁=R₂ SERIES)M

FEATURES

- Epitaxial planar die construction.
- Complementary NPN types available(DTC).
- Built-in biasing resistors,R₁=R₂.
- Also available in lead free version.

HF



APPLICATIONS

- The PNP style digital transistor.

ORDERING INFORMATION

Type No.	Marking	Package Code
DTA114EM	14	SOT-723
DTA124EM	15	SOT-723
DTA143EM	13	SOT-723
DTA144EM	16	SOT-723

MAXIMUM RATING @ Ta=25°C unless otherwise specified

Symbol	Parameter	Value	Units
V _{cc}	Supply Voltage	-50	V
V _{IN}	Input Voltage	+10 to -40	V
	DTA114EM	+10 to -40	
	DTA124EM	+10 to -40	
	DTA143EM	+10 to -30	
I _O	Output Current	+10 to -40	mA
	DTA114EM	-50	
	DTA124EM	-30	
	DTA143EM	-100	
I _C (Max.)	Output current ALL	-30	mA
P _D	Power Dissipation	-100	
R _{θJA}	Thermal Resistance, Junction to Ambient Air	100	mW
T _j , T _{stg}	Operating and Storage and Temperature Range	1250	°C/W
		-55 to +150	°C

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ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Input Voltage	V _{I(off)}	V _{CC} =-5V,I _O =-100μA	-0.5	-1.1	-	
Input Voltage DTA114EM DTA124EM DTA143EM DTA144EM	V _{I(on)}	V _O =-0.3V,I _O =-10mA	-	-1.9	-3	V
		V _O =-0.2V,I _O =-5mA				
		V _O =-0.3V,I _O =-20mA				
		V _O =-0.3V,I _O =-2mA				
Output Voltage DTA114EM DTA124EM DTA143EM DTA144EM	V _{O(on)}	I _O /I _I =-10mA/-0.5mA,	-	-0.1	-0.3	V
		I _O /I _I =-0.5mA/-0.1mA				
		I _O /I _I =-0.1mA/-0.05mA				
		I _O /I _I =-0.05mA/-0.02mA				
Input Current DTA114EM DTA124EM DTA143EM DTA144EM	I _I	V _I =-5V	-	-	-0.88 -0.36 -1.8 -0.18	mA
		V _I =-10V				
		V _I =-20V				
		V _I =-50V				
Output Current	I _{O(off)}	V _{CC} =-50V,V _I =0V	-	-	-0.5	μA
DC Current Gain DTA114EM DTA124EM DTA143EM DTA144EM	G _I	V _O =-5V,I _O =-5mA	30	-	-	
		V _O =-5V,I _O =-5mA	56			
		V _O =-5V,I _O =-10mA	20			
		V _O =-5V,I _O =-5mA	68			
Input Resistor DTA114EM DTA124EM DTA143EM DTA144EM	R ₁ (R ₂)		7	10	13	kΩ
			15.4	22	28.6	
			3.29	4.7	6.11	
			32.9	47	61.1	
Resistance Ratio	R ₂ /R ₁	-	0.8	1	1.2	
Gain-Bandwidth Product	f _T	V _{CE} =-10V,I _E =5mA,f=100MHz	-	250	-	MHz

TYPICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified

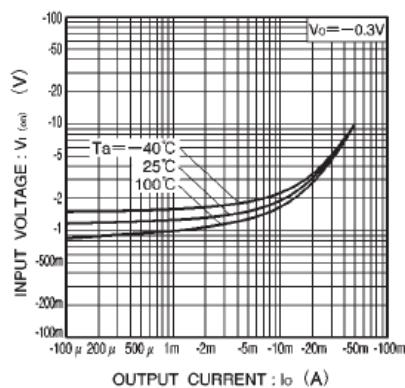


Fig.1 Input voltage vs. output current (ON characteristics)

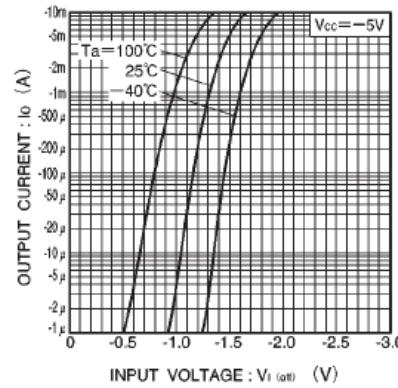


Fig.2 Output current vs. input voltage (OFF characteristics)

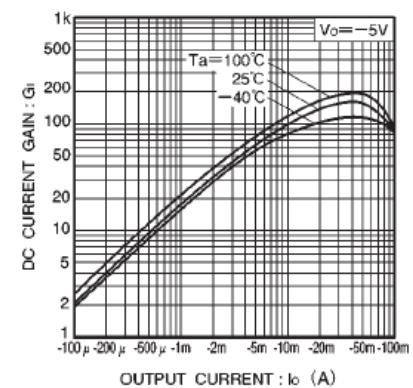


Fig.3 DC current gain vs. output current

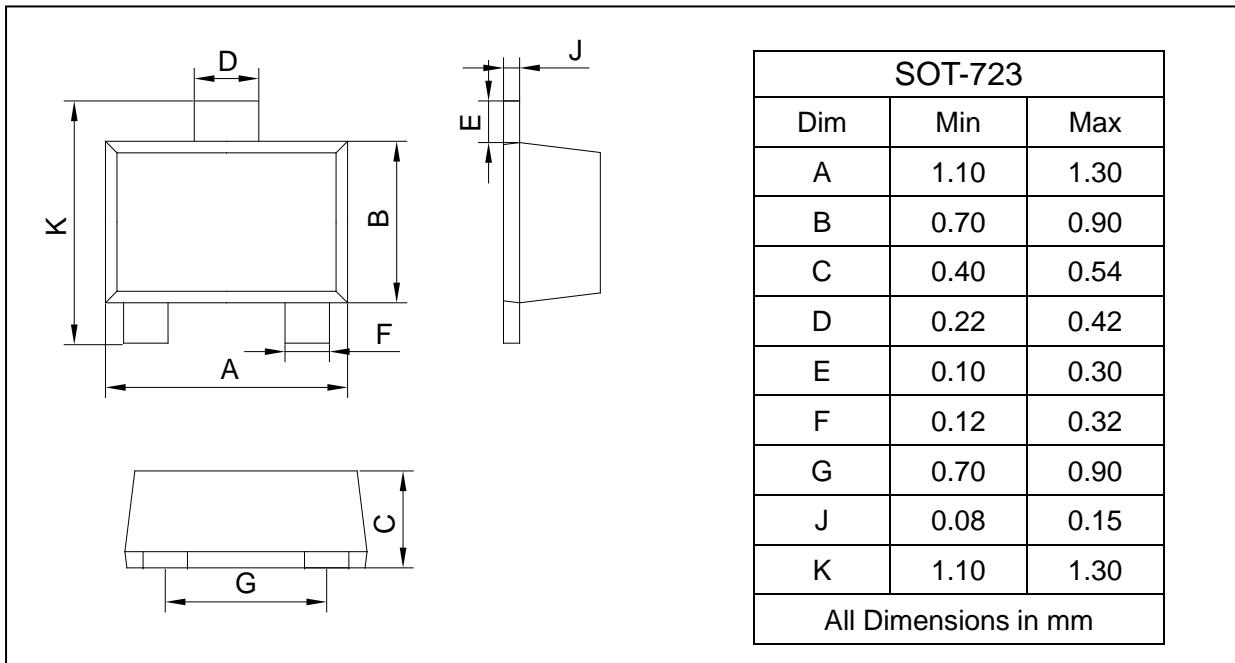
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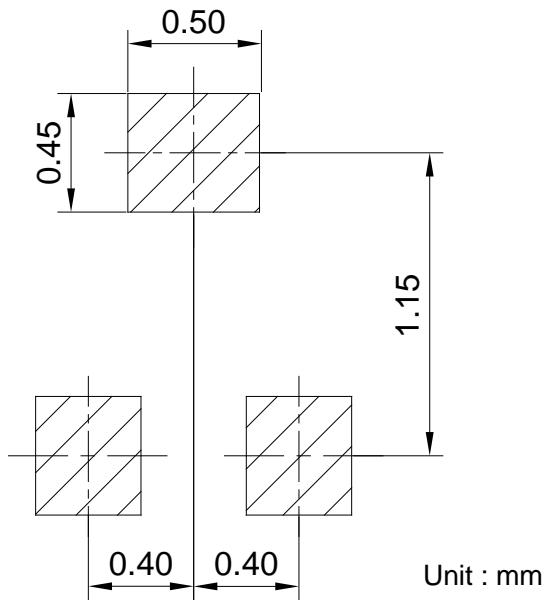
PACKAGE OUTLINE

Plastic surface mounted package

SOT-723



SOLDERING FOOTPRINT



PACKAGE INFORMATION

Device	Package	Shipping
DTA114EM/124EM/143EM/144EM	SOT-723	10000pcs / Tape & Reel